

Vishay General Semiconductor

Surface Mount Glass Passivated Ultrafast Rectifier

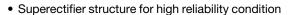
SUPERECTIFIER®



DO-214BA (GF1)

PRIMARY CHARACTERISTICS						
I _{F(AV)}	1.0 A					
V _{RRM}	50 V to 200 V					
I _{FSM}	30 A					
t _{rr}	50 ns					
V _F	1.0 V					
T _J max.	175 °C					

FEATURES





- · Cavity-free glass-passivated junction
- Ideal for automated placement
- Ultrafast reverse recovery time
- · Low switching losses, high efficiency
- Lliab forward average conshility
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214BA, molded epoxy over glass body Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT	
Device marking code		EA	EB	EC	ED		
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V	
Maximum RMS voltage	V _{RMS}	35	70	105	140	V	
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V	
Maximum average forward rectified current at T _L = 125 °C	I _{F(AV)}		А				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30				А	
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175				°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT
Maximum instantaneous forward voltage	1.0 A		V _F ⁽¹⁾	1.0			V	
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C	I_ (1)	I _R ⁽¹⁾ 5.0			μA	
		T _A = 125 °C	'R ''					μΑ
Typical reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	50				ns
Typical junction capacitance	4.0 V, 1 MHz		CJ	15				pF

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	L EGF1A EGF1B EGF1C EGF1D		EGF1D	UNIT		
Typical thermal resistance	R _{0JA} (1)	85				°C/W	
	R _{0JL} (1)	30					

Note

⁽¹⁾ Thermal resistance from junction to ambient and from junction to lead, PCB mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
EGF1D-E3/67A	0.104	67A	1500	7" diameter plastic tape and reel			
EGF1D-E3/5CA	0.104	5CA	6500	13" diameter plastic tape and reel			
EGF1DHE3/67A (1)	0.104	67A	1500	7" diameter plastic tape and reel			
EGF1DHE3/5CA (1)	0.104	5CA	6500	13" diameter plastic tape and reel			

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise specified)

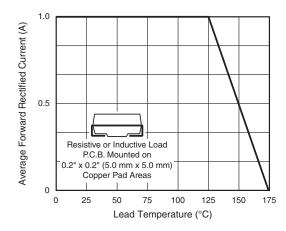


Fig. 1 - Maximum Forward Current Derating Curve

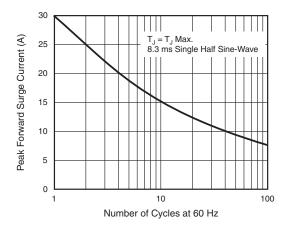


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

⁽¹⁾ AEC-Q101 qualified



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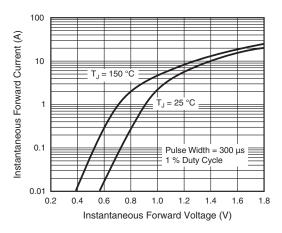
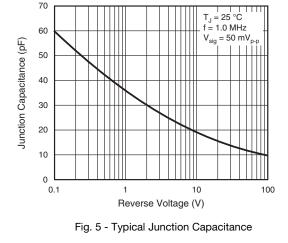


Fig. 3 - Typical Instantaneous Forward Characteristics



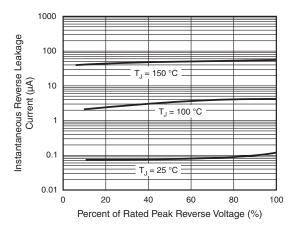


Fig. 4 - Typical Reverse Leakage Characteristics

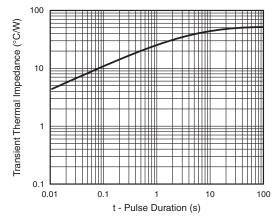


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214BA (GF1) Cathode Band **Mounting Pad Layout** 0.066 (1.68) 0.076 (1.93) 0.066 (1.68) MAX. 0.040 (1.02) MIN. 0.187 (4.75) 0.167 (4.24) 0.015 (0.38) 0.0065 (0.17) 0.060 (1.52) 0.118 (3.00) 0.108 (2.74) 0.098 (2.49) 0.100 (2.54) 0.220 (5.58) REF. 0.114 (2.90) 0.006 (0.152) TYP 0.060 (1.52) 0.094 (2.39) 0.030 (0.76) 0.226 (5.74) 0.196 (4.98)

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